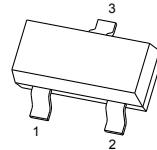


V_{(BR)DSS}	R_{D(on)MAX}	I_D
20V	0.100Ω@-4.5V	0.5A
	0.150Ω@-2.5V	

SOT-23


- 1.GATE
-
- 2.SOURCE
-
- 3.DRAIN

General FEATURE

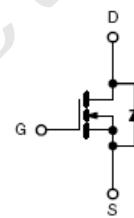
- TrenchFET Power MOSFET
- Lead free product is acquired
- Surface mount package

APPLICATION

- Load Switch for Portable Devices
- DC/DC Converter

MARKING


*w: week code

Equivalent Circuit

Maximum ratings (T_a=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	20	V
Gate-Source Voltage	V _{GS}	±12	
Continuous Drain Current	I _D	0.5	A
Pulsed Drain Current*1	I _{DM}	4.0	
Continuous Source-Drain Diode Current	I _S	1.0	
Maximum Power Dissipation	P _D	0.5	W
Thermal Resistance from Junction to Ambient(t ≤5s)	R _{θJA}	250	°C/W
Junction Temperature	T _J	150	°C
Storage Temperature	T _{stg}	-55 ~+150	

Note :

*1. Pulse Width ≤ 300μs, Duty cycle ≤2%

MOSFET ELECTRICAL CHARACTERISTICS

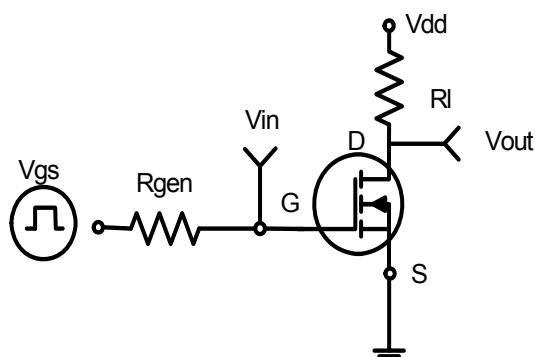
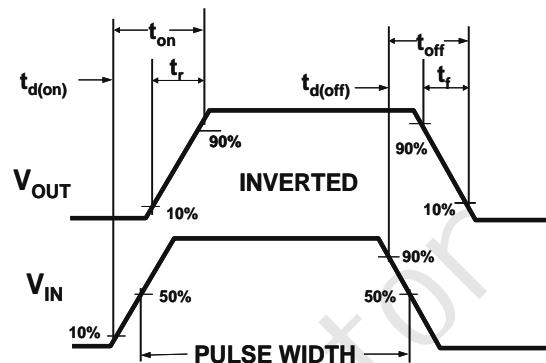
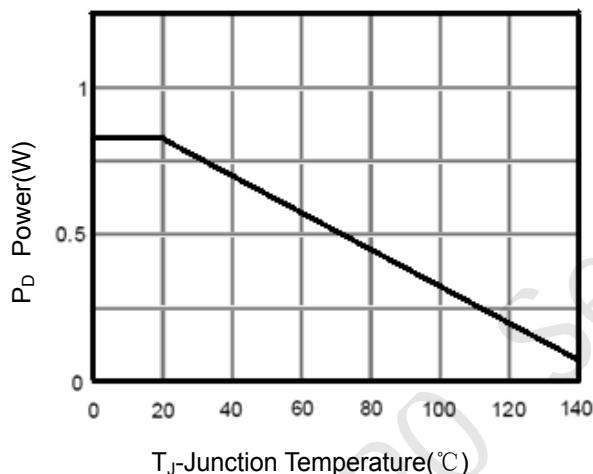
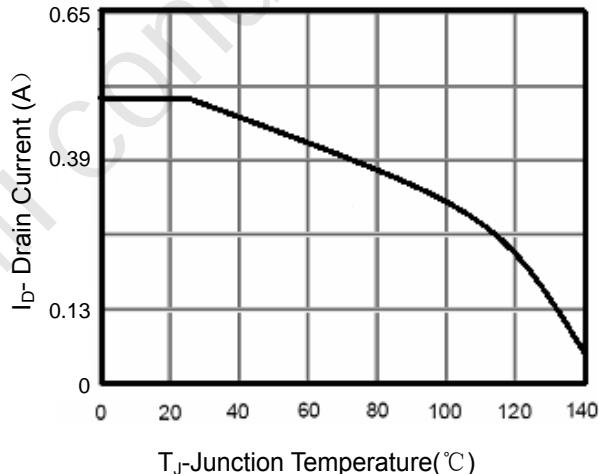
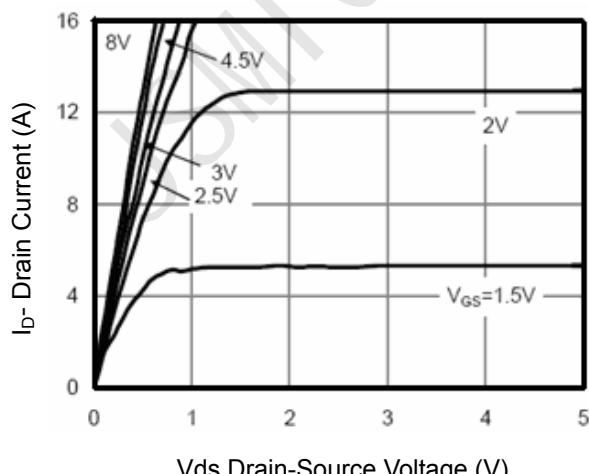
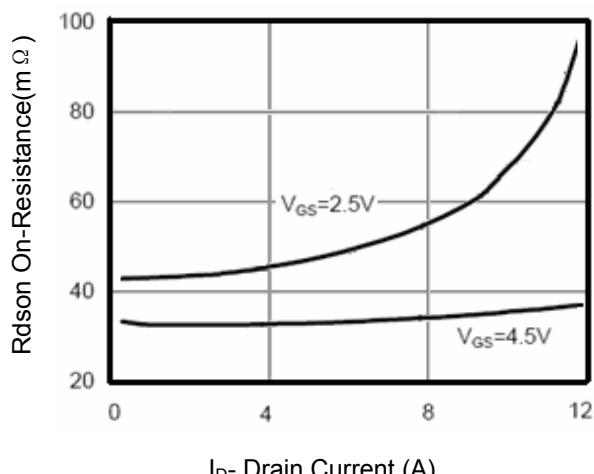
Ta =25 °C unless otherwise specified

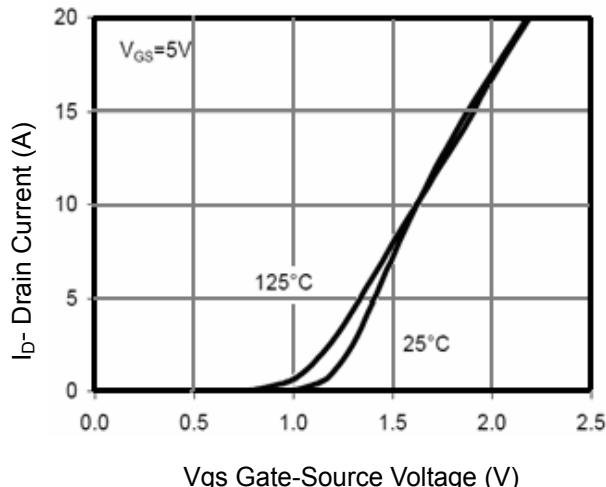
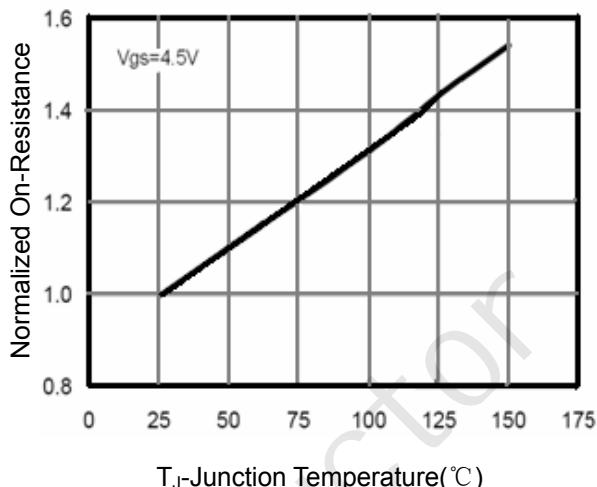
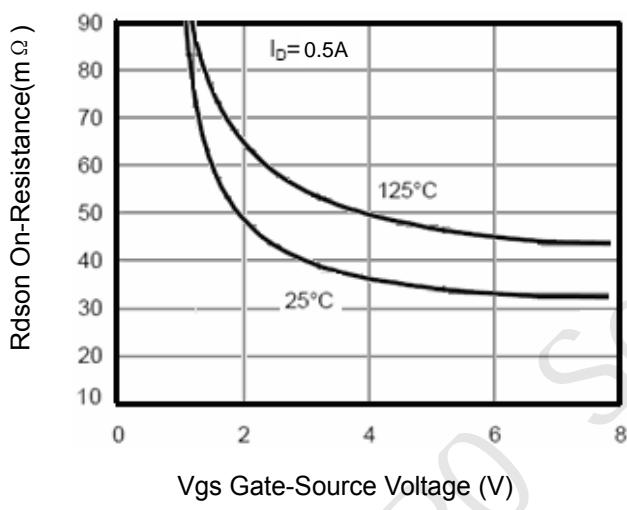
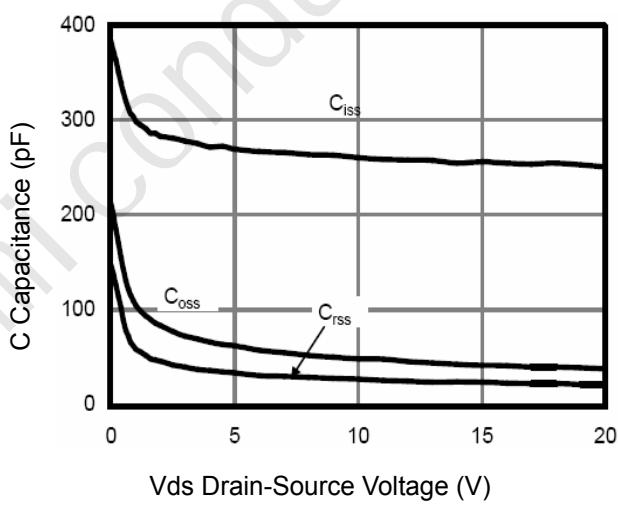
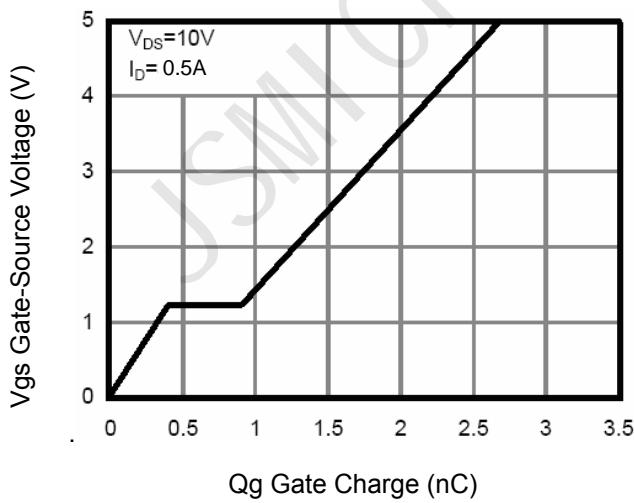
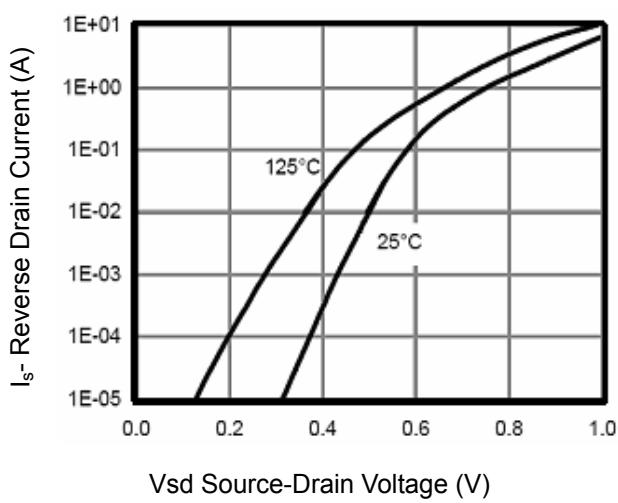
Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Static						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = -250μA	20			V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250μA	0.5	0.8	1.0	
Gate-source leakage	I _{GSS}	V _{DS} = 0V, V _{GS} = ±12V			±100	nA
Zero gate voltage drain current	I _{DSS}	V _{DS} = 16V, V _{GS} = 0V			1	μA
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 4.5V, I _D = 0.5A		0.085	0.100	Ω
		V _{GS} = 2.5V, I _D = 0.5A		0.135	0.150	
Forward transconductance ^a	g _{fs}	V _{DS} = 5V, I _D = 0.5A		8.0	-	S
Dynamic^b						
Input capacitance	C _{iss}	V _{DS} = 10V, V _{GS} = 0V, f = 1MHz		300		pF
Output capacitance	C _{oss}			120		
Reverse transfer capacitance	C _{rss}			80		
Total gate charge	Q _g	V _{DS} = 10V, V _{GS} = 4.5V, I _D = 0.5A		4.0		nC
Gate-source charge	Q _{gs}			0.65		
Gate-drain charge	Q _{gd}			1.6		
Turn-on delay time	t _{d(on)}	V _{DD} = 10V, I _D = 0.5A V _{GEN} = 4.5V, R _G = 6Ω		15.0		ns
Rise time	t _r			85.0		
Turn-off delay time	t _{d(off)}			45.0		
Fall time	t _f			20.0		
Drain-source body diode characteristics						
Continuous source-drain diode current	I _s	T _c = 25°C			1.0	A
Body diode voltage	V _{SD}	I _s = 1.0A		0.7	1.3	

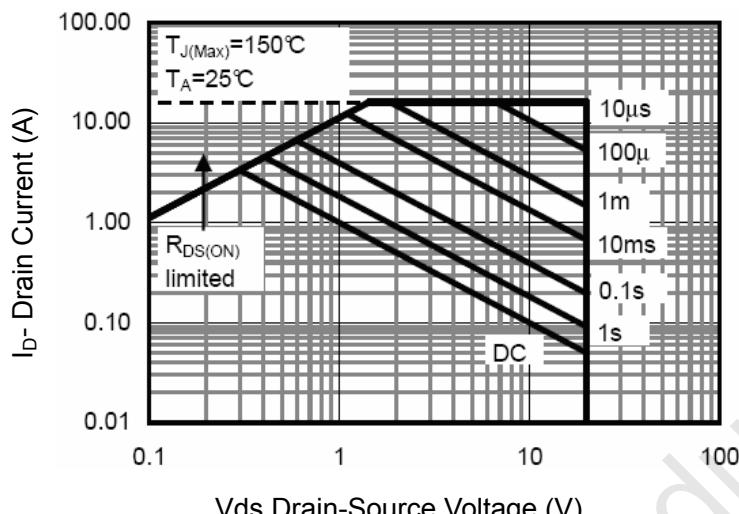
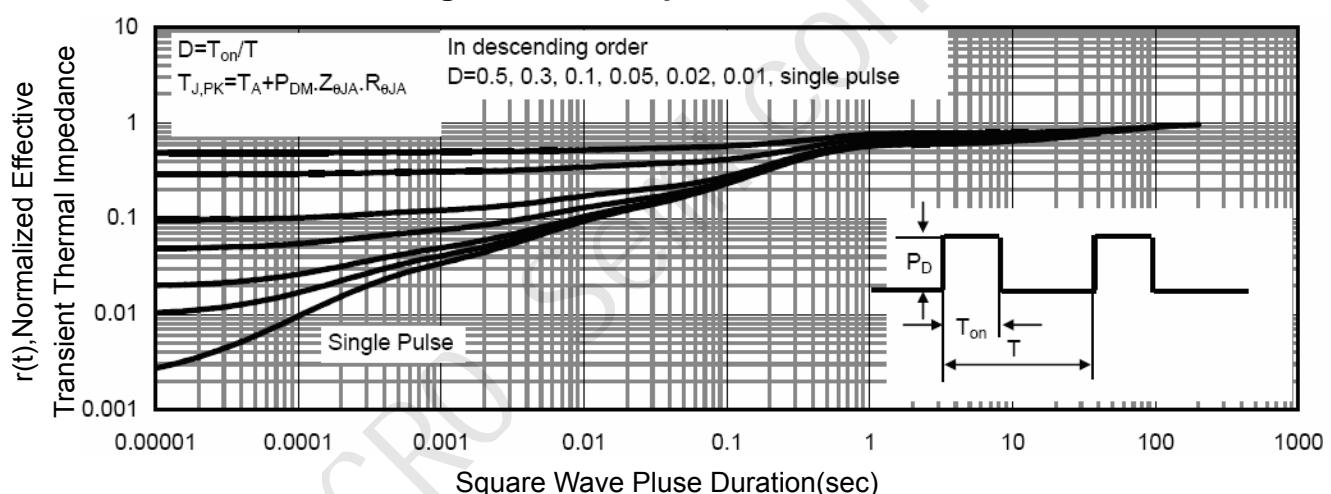
Notes :

a.Pulse Test : Pulse Width < 300μs, Duty Cycle ≤2%.

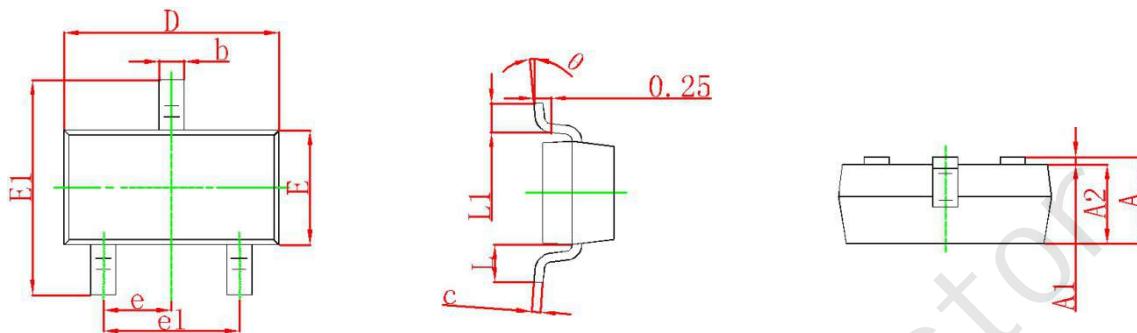
b.Guaranteed by design, not subject to production testing.

Typical Electrical and Thermal Characteristics

Figure 1:Switching Test Circuit

Figure 2:Switching Waveforms

Figure 3 Power Dissipation

Figure 4 Drain Current

Figure 5 Output Characteristics

Figure 6 Drain-Source On-Resistance


Figure 7 Transfer Characteristics

Figure 8 Drain-Source On-Resistance

Figure 9 Rdson vs Vgs

Figure 10 Capacitance vs Vds

Figure 11 Gate Charge

Figure 12 Source-Drain Diode Forward

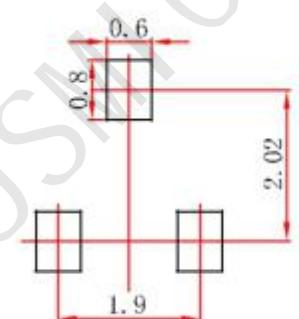

Figure 13 Safe Operation Area

Figure 14 Normalized Maximum Transient Thermal Impedance

SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23 Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

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